

## Product Specification

### PE42850

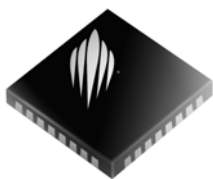
UltraCMOS® SP5T RF Switch  
30 - 1000 MHz

#### Product Description

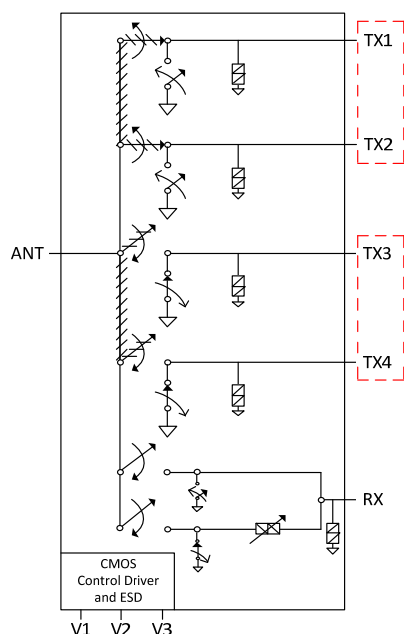
The PE42850 is a HaRP™ technology-enhanced SP5T high power RF switch supporting wireless applications up to 1 GHz. It offers maximum power handling of 42.5 dBm continuous wave (CW). It delivers high linearity and excellent harmonics performance. It has both a standard and attenuated RX mode. No blocking capacitors are required if DC voltage is not present on the RF ports.

The PE42850 is manufactured on Peregrine's UltraCMOS® process, a patented variation of silicon-on-insulator (SOI) technology on a sapphire substrate, offering the performance of GaAs with the economy and integration of conventional CMOS.

**Figure 1. Package Type**  
32-lead 5x5 mm QFN

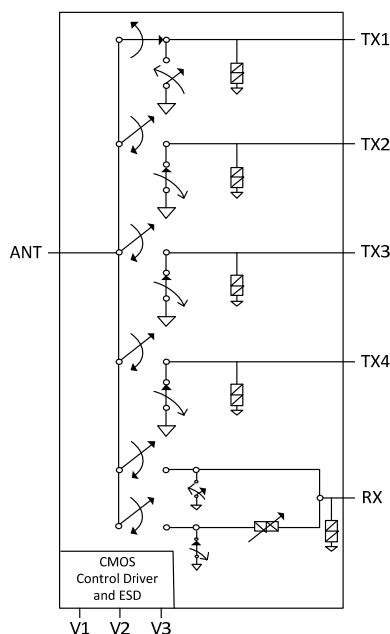


**Figure 2. Functional Diagram of SP3T Configuration**



ANT can be tied to TX1 and TX2 or TX3 and TX4

**Figure 3. Functional Diagram of SP5T Configuration**



SP5T, standard configuration

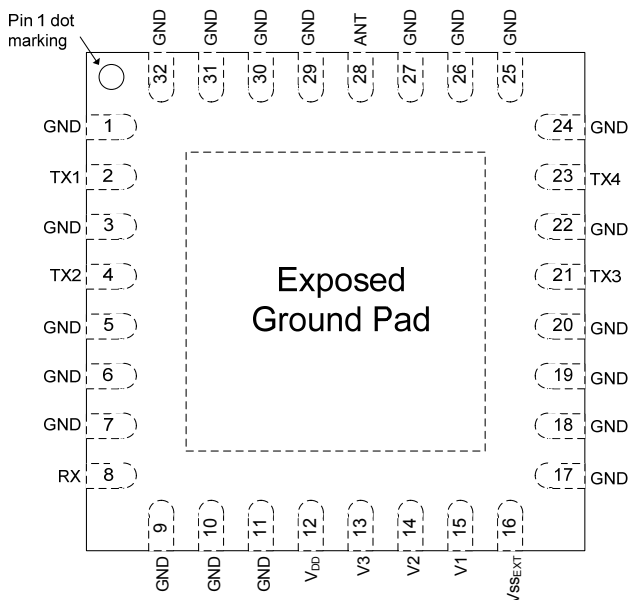
DOC-02178

**Table 1. Electrical Specifications @ -40 to +85°C, V<sub>DD</sub> = 2.3 to 5.5V, V<sub>SS</sub><sub>EXT</sub> = 0V or V<sub>DD</sub> = 3.4 to 5.5V, V<sub>SS</sub><sub>EXT</sub> = -3.4V (Z<sub>S</sub> = Z<sub>L</sub> = 50Ω ) unless otherwise noted<sup>1</sup>**

Parameter	Path	Condition	Min	Typ	Max	Unit
Operating frequency			30		1000	MHz
Insertion loss <sup>2</sup>	ANT-TX	Active TX port 1, 2, 3 or 4 @ rated power (-40°C, +25°C) 30–520 MHz 520–1000 MHz		0.25 0.35	0.30 0.45	dB dB
		Active TX port 1, 2, 3 or 4 @ rated power (+85°C) 30–520 MHz 520–1000 MHz		0.30 0.45	0.35 0.55	dB dB
Insertion loss <sup>2</sup> (un-attenuated state)	ANT-RX	Active RX port (-40°C, +25°C) 30–520 MHz 520–1000 MHz		0.50 0.65	0.60 0.80	dB dB
		Active RX port (+85°C) 30–520 MHz 520–1000 MHz		0.60 0.70	0.70 0.85	dB dB
		1575 MHz for GPS RX, < -10 dBm, +25°C		1	1.2	dB
Insertion loss <sup>2</sup> (attenuated state)	ANT-RX	Active RX port 30–1000 MHz	15.2	16	16.8	dB
Isolation (supply biased)	TX - TX	30–520 MHz 520–1000 MHz	33 29	36 30		dB dB
		30–520 MHz 520–1000 MHz	34 29	36 30		dB dB
Isolation (supply biased)	TX - RX	30–520 MHz 520–1000 MHz	34 29	36 30		dB dB
Unbiased isolation V <sub>DD</sub> , V1, V2, V3 = 0V	ANT - TX	+27 dBm	6			dB
Unbiased isolation V <sub>DD</sub> , V1, V2, V3 = 0V	ANT - RX	+27 dBm	14			dB
Return loss <sup>2</sup>	ANT-RX	Un-attenuated state 30–520 MHz 520–1000 MHz	22 18	27 22		dB dB
		Un-attenuated state, 1575 MHz for GPS RX, < -10 dBm, +25°C	10	14		dB
		Attenuated state, optimized without attenuator engaged 30–520 MHz 520–1000 MHz	16 13	21 18		dB dB
Return loss <sup>2</sup>	ANT-TX	30–520 MHz 520–1000 MHz	21 15	28 17		dB dB
		30–520 MHz @ +40.0 dBm 521–870 MHz @ +38.5 dBm 871–1000 MHz @ +37.5 dBm		-90	-81	dBc
2nd and 3rd harmonic (< 1.15:1 VSWR)	TX	30–520 MHz @ +40.0 dBm (pulsed signal, at 10% duty cycle <sup>3</sup> ) 521–870 MHz @ +38.5 dBm (pulsed signal, at 10% duty cycle <sup>3</sup> ) 871–1000 MHz @ +37.5 dBm (pulsed signal, at 10% duty cycle <sup>3</sup> )		-82	-74	dBc
2nd and 3rd harmonic (50Ω source/load impedance)	TX	30–1000 MHz @ +45.0 dBm (pulsed signal, at 10% duty cycle <sup>3</sup> )		-80	-71	dBc
2nd and 3rd harmonic (50Ω source/load impedance)	TX	30–1000 MHz @ +42.5 dBm (CW)		-84	-75	dBc
Input 0.1 dB compression point <sup>4</sup>	ANT-TX	1000 MHz		45.5		dBm
IIP3	RX	Un-attenuated state	42			dBm
		Attenuated state	33			dBm
Settling time		From 50% control until harmonics within specifications		30	70	μs
Switching time		50% CTRL to 90% or 10% RF		15		μs

Notes: 1. In a 2TX-1RX SP3T configuration, TX1 and TX2 are tied and TX3 and TX4 are tied respectively. Refer to Application Note AN35 for SP3T performance data  
2. Narrow trace widths are used near each port to improve impedance matching. Refer to evaluation board layouts (Figure 23) and schematic (Figure 24) for details  
3. 10% of 4620 μs period  
4. The input 0.1 dB compression point is a linearity figure of merit. Refer to Table 3 for the RF input power P<sub>IN</sub>

**Figure 4. Pin Configuration (Top View)<sup>1</sup>**



Note 1: Pins 1, 3, 5, 7, 9, 10, 17, 19, 20, 22, 24, 26, 27, 29, 30 and 31 can be N/C if deemed necessary by the customer

**Table 2. Pin Descriptions**

Pin #	Pin Name	Description
1, 3, 5-7, 9-11, 17-20, 22, 24-27, 29-32	GND	Ground
2	TX1 <sup>2</sup>	Transmit pin 1
4	TX2 <sup>1,2</sup>	Transmit pin 2
8	RX <sup>2</sup>	Receive pin
12	V <sub>DD</sub>	Supply voltage (nominal 3.3V)
13	V3	Digital control logic input 3
14	V2	Digital control logic input 2
15	V1	Digital control logic input 1
16	V <sub>SS</sub> EXT <sup>3</sup>	External Vss negative voltage control
21	TX3 <sup>2</sup>	Transmit pin 3
23	TX4 <sup>1,2</sup>	Transmit pin 4
28	ANT <sup>2</sup>	Antenna pin
Pad	GND	Exposed pad: ground for proper operation

Notes: 1. To operate the part as a 2TX-1RX SP3T, tie TX1 to TX2 and TX3 to TX4 respectively. Refer to Application Note AN35 for SP3T performance data  
2. RF pins 2, 4, 8, 21, 23 and 28 must be at 0V DC. The RF pins do not require DC blocking capacitors for proper operation if the 0V DC requirement is met  
3. Use V<sub>SS</sub>EXT (pin 16, V<sub>SS</sub>EXT = -V<sub>DD</sub>) to bypass and disable internal negative voltage generator. Connect V<sub>SS</sub>EXT (pin 16) to GND (V<sub>SS</sub>EXT = 0V) to enable internal negative voltage generator

**Table 3. Operating Ranges<sup>1</sup>**

Parameter	Symbol	Min	Typ	Max	Unit
Supply voltage (normal mode, V <sub>SS</sub> EXT = 0V)	V <sub>DD</sub>	2.3		5.5	V
Supply voltage (bypass mode, V <sub>SS</sub> EXT = -3.4V, V <sub>DD</sub> ≥ 3.4V for full spec. compliance)	V <sub>DD</sub>	2.7	3.4	5.5	V
Negative supply voltage (bypass mode)	V <sub>SS</sub> EXT	-3.6		-3.2	V
Supply current (normal mode, V <sub>SS</sub> EXT = 0V)	I <sub>DD</sub>		130	200	μA
Supply current (bypass mode, V <sub>SS</sub> EXT = -3.4V)	I <sub>DD</sub>		50	80	μA
Negative supply current (bypass mode, V <sub>SS</sub> EXT = -3.4V)	I <sub>SS</sub>	-40	-16		μA
Digital input high (V1, V2, V3)	V <sub>IH</sub>	1.17		3.6	V
Digital input low (V1, V2, V3)	V <sub>IL</sub>	-0.3		0.6	V
TX RF input power <sup>2,3</sup> (VSWR ≤ 8:1)	P <sub>IN-TX</sub>			40	dBm
TX RF input power <sup>2,3</sup> (50Ω source/load impedance)	P <sub>IN-TX</sub>			45	dBm
TX RF input power <sup>2</sup> (50Ω source/load impedance, CW)	P <sub>IN-TX</sub>			42.5	dBm
ANT RF input power, unbiased (VSWR ≤ 8:1)	P <sub>IN-ANT</sub>			27	dBm
RX RF input power <sup>2</sup> (VSWR ≤ 8:1)	P <sub>IN-RX</sub>			27	dBm
Operating temperature range (case)	T <sub>OP</sub>	-40		85	°C
Operating junction temperature	T <sub>j</sub>			135	°C

Notes: 1. In a 2TX-1RX SP3T configuration, TX1 and TX2 are tied and TX3 and TX4 are tied respectively. Refer to Application Note AN35 for SP3T performance data  
2. Supply biased  
3. Pulsed, 10% duty cycle of 4620 μs period

**Table 4. Absolute Maximum Ratings**

Parameter/Condition	Symbol	Min	Max	Unit
Supply voltage	V <sub>DD</sub>	-0.3	5.5	V
Digital input voltage (V1, V2, V3)	V <sub>CTRL</sub>	-0.3	3.6	V
TX RF input power <sup>1</sup> (50Ω source/load impedance)	P <sub>IN-TX</sub>		45	dBm
TX RF input power <sup>1</sup> (VSWR ≤ 8:1)	P <sub>IN-TX</sub>		40	dBm
ANT RF input power, unbiased (VSWR ≤ 8:1)	P <sub>IN-ANT</sub>		27	dBm
RX RF input power <sup>1</sup> (VSWR ≤ 8:1)	P <sub>IN-RX</sub>		27	dBm
Storage temperature range	T <sub>ST</sub>	-65	150	°C
Maximum case temperature	T <sub>CASE</sub>		85	°C
Peak maximum junction temperature (10 seconds max)	T <sub>j</sub>		200	°C
ESD voltage HBM <sup>2</sup> , all pins	V <sub>ESD</sub>		1500	V
ESD Voltage MM <sup>3</sup> , all pins	V <sub>ESD</sub>		200	V

Notes: 1. Supply biased  
2. Human Body Model (MIL-STD 883 Method 3015)  
3. Machine Model (JEDEC JESD22-A115)

Exceeding absolute maximum ratings may cause permanent damage. Operation should be restricted to the limits in the Operating Ranges table. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

### Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS<sup>®</sup> device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the rating specified.

### Latch-Up Avoidance

Unlike conventional CMOS devices, UltraCMOS<sup>®</sup> devices are immune to latch-up.

### Moisture Sensitivity Level

The Moisture Sensitivity Level rating for the 5x5 mm QFN package is MSL3.

### Switching Frequency

The PE42850 has a maximum 10 kHz switching rate when the internal negative voltage generator is used (pin 16 = GND). The rate at which the PE42850 can be switched is only limited to the switching time (*Table 1*) if an external negative supply is provided (pin 16 = V<sub>SSEXT</sub>).

Switching frequency describes the time duration between switching events. Switching time is the time duration between the point the control signal reaches 50% of the final value and the point the output signal reaches within 10% or 90% of its target value.

### Optional External V<sub>SS</sub> Control (V<sub>SSEXT</sub>)

For proper operation, the V<sub>SSEXT</sub> control pin must be grounded or tied to the V<sub>SS</sub> voltage specified in *Table 3*. When the V<sub>SSEXT</sub> control pin is grounded, FETs in the switch are biased with an internal voltage generator. For applications that require the lowest possible spur performance, V<sub>SSEXT</sub> can be applied externally to bypass the internal negative voltage generator.

### Spurious Performance

The typical spurious performance of the PE42850 is -130 dBm when V<sub>SSEXT</sub> = 0V (pin 16 = GND). If further improvement is desired, the internal negative voltage generator can be disabled by setting V<sub>SSEXT</sub> = -3.4V.

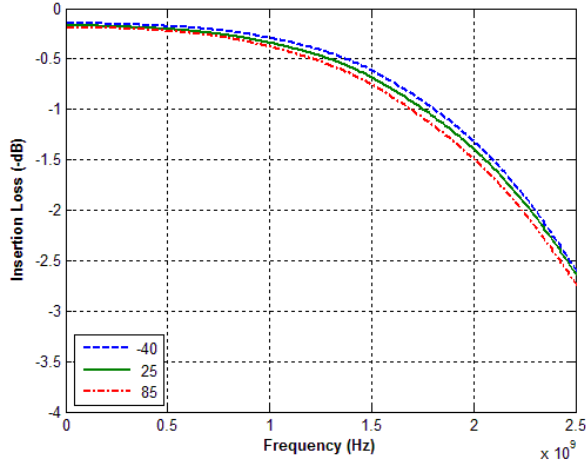
**Table 5. Truth Table**

Path	V3	V2	V1
ANT – RX Attenuated	L	L	L
ANT – TX1	L	L	H
ANT – TX2	L	H	L
ANT – TX1 and TX2 <sup>1</sup>	L	H	H
ANT – RX	H	L	L
ANT – TX3	H	L	H
ANT – TX4	H	H	L
ANT – TX3 and TX4 <sup>1</sup>	H	H	H

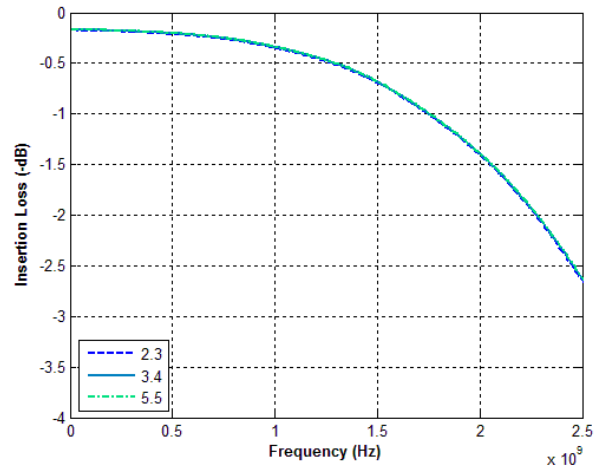
Note 1: In a 2TX-1RX SP3T configuration, TX1 and TX2 are tied and TX3 and TX4 are tied respectively. Refer to Application Note AN35 for SP3T performance data

Typical Performance Data @ 25°C and  $V_{DD} = 3.4V$  unless otherwise specified

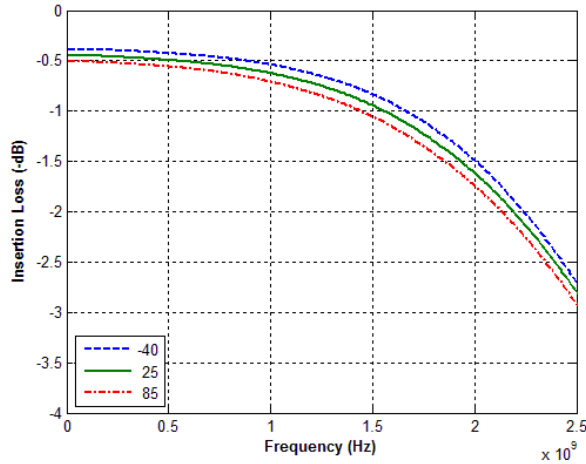
**Figure 5. Insertion Loss vs. Temp (TX)**



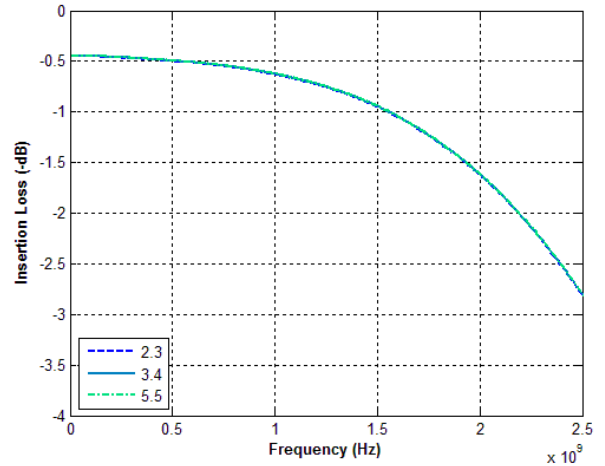
**Figure 6. Insertion Loss vs.  $V_{DD}$  (TX)**



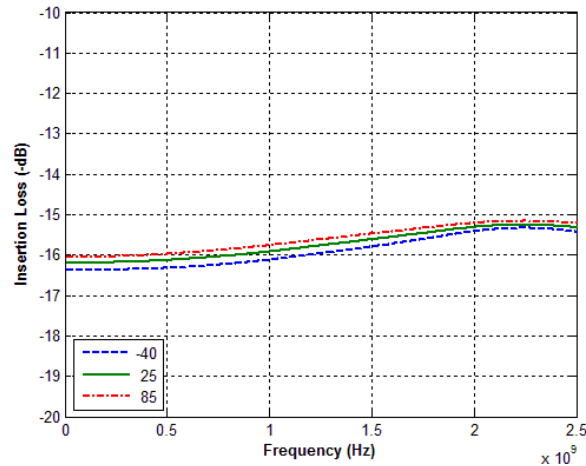
**Figure 7. Insertion Loss vs. Temp (RX, Un-Attenuated)**



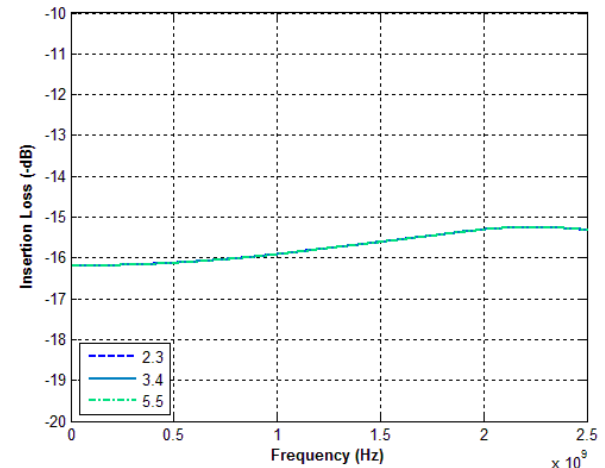
**Figure 8. Insertion Loss vs.  $V_{DD}$  (RX, Un-Attenuated)**



**Figure 9. Insertion Loss vs. Temp (RX, Attenuated)**

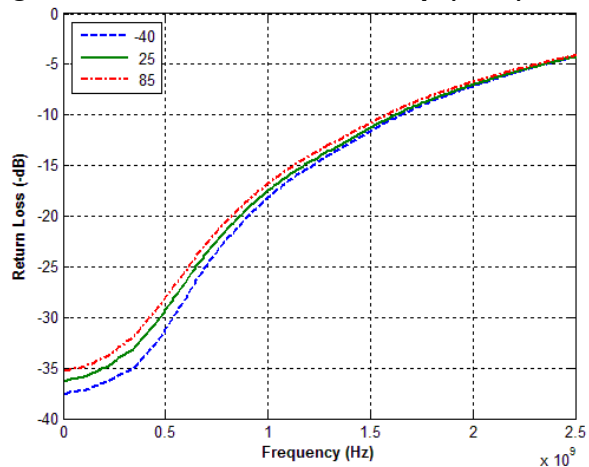


**Figure 10. Insertion Loss vs.  $V_{DD}$  (RX, Attenuated)**

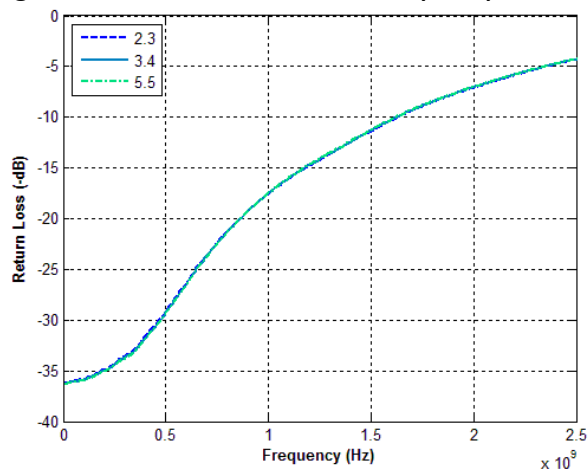


Typical Performance Data @ 25°C and  $V_{DD} = 3.4V$  unless otherwise specified

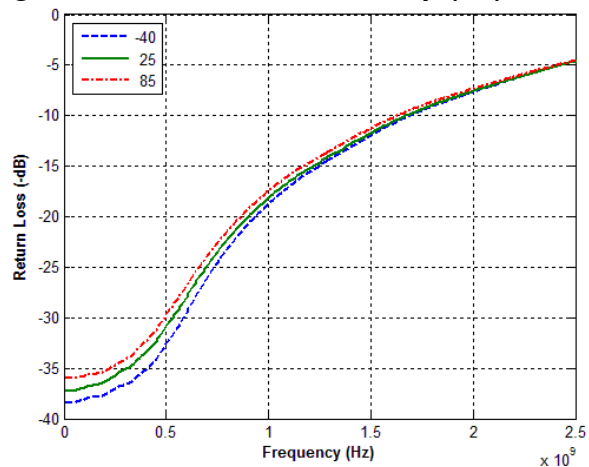
**Figure 11. Return Loss vs. Temp (ANT)**



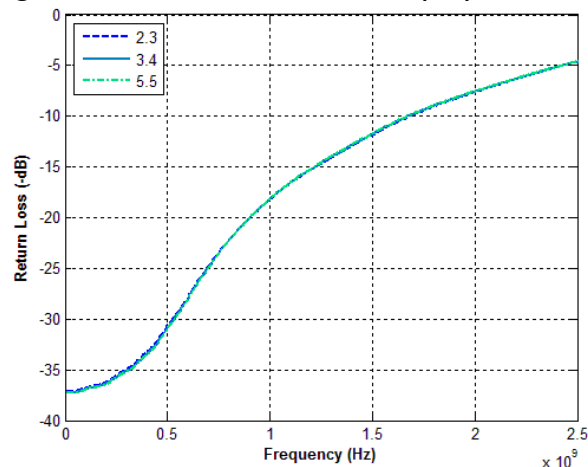
**Figure 12. Return Loss vs.  $V_{DD}$  (ANT)**



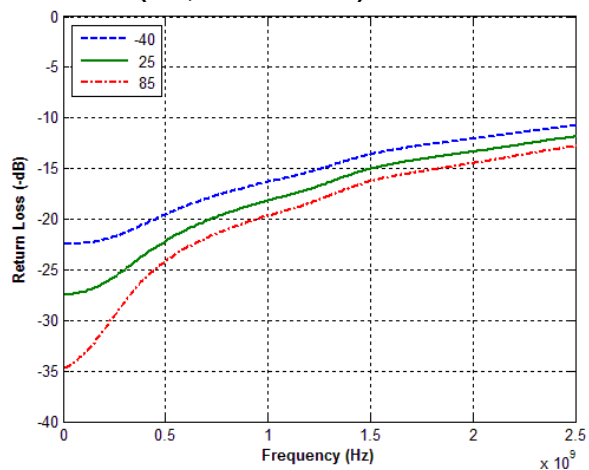
**Figure 13. Return Loss vs. Temp (TX)**



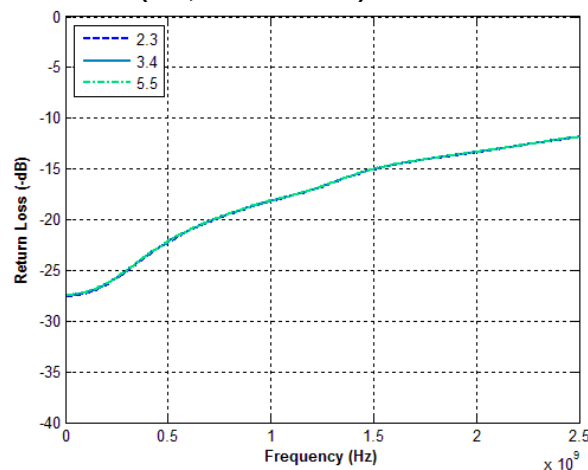
**Figure 14. Return Loss vs.  $V_{DD}$  (TX)**



**Figure 15. Return Loss vs. Temp (RX, Attenuated)**

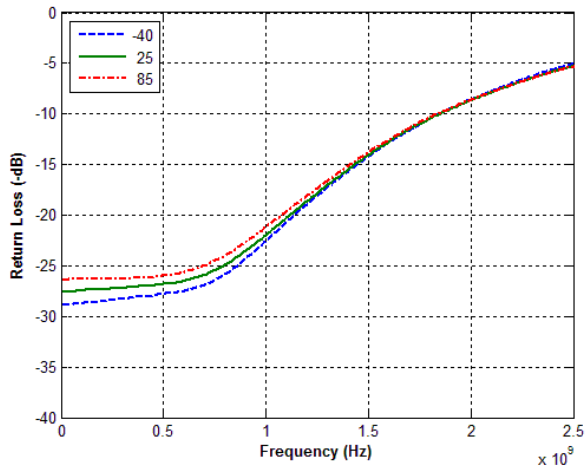


**Figure 16. Return Loss vs.  $V_{DD}$  (RX, Attenuated)**

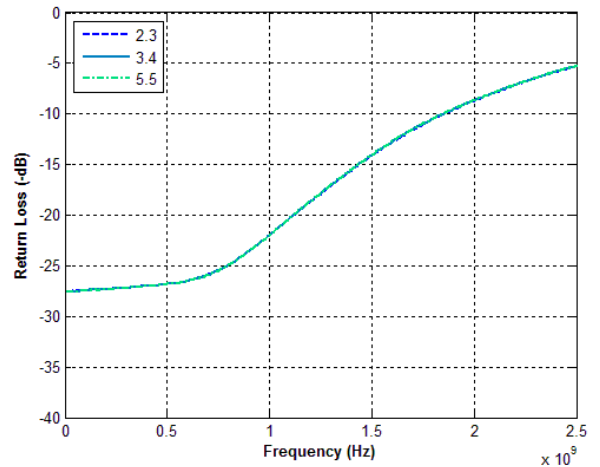


Typical Performance Data @ 25°C and  $V_{DD} = 3.4V$  unless otherwise specified

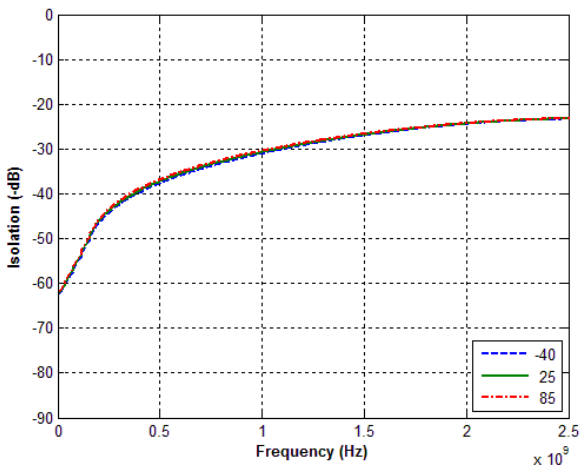
**Figure 17. Return Loss vs. Temp  
(RX, Un-Attenuated)**



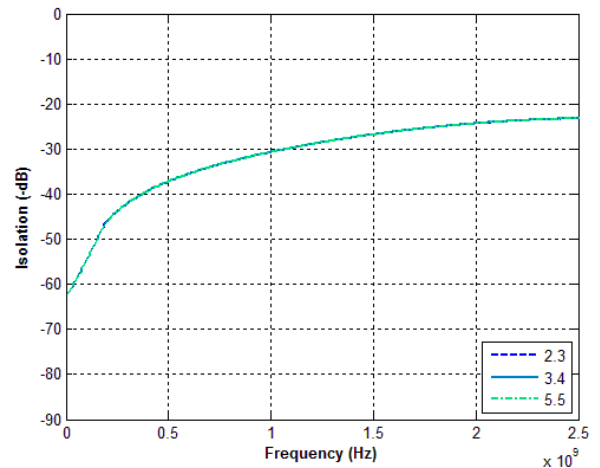
**Figure 18. Return Loss vs.  $V_{DD}$   
(RX, Un-Attenuated)**



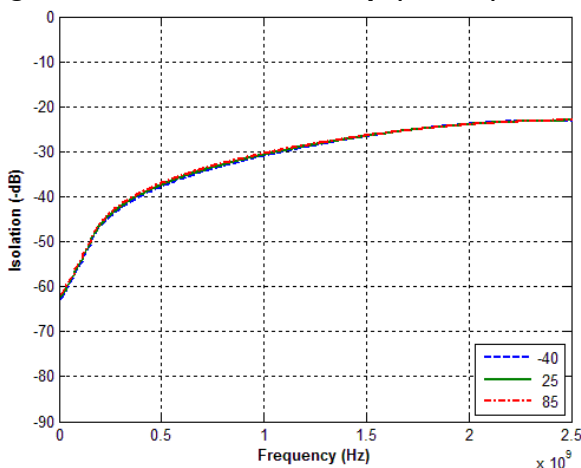
**Figure 19. Isolation vs. Temp (TX-TX)**



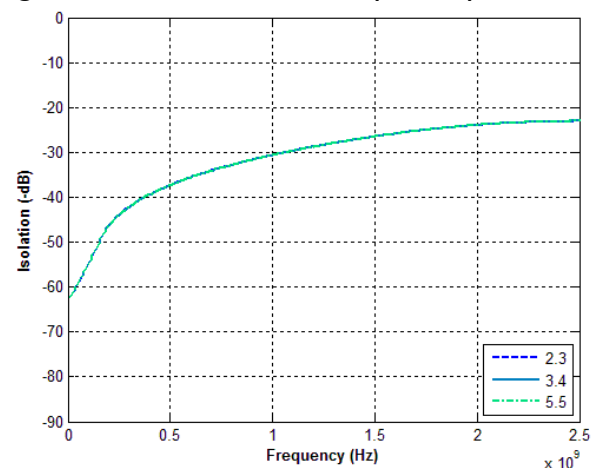
**Figure 20. Isolation vs.  $V_{DD}$  (TX-TX)**



**Figure 21. Isolation vs. Temp (TX-RX)**



**Figure 22. Isolation vs.  $V_{DD}$  (TX-RX)**



## Thermal Data

Though the insertion loss for this part is very low, when handling high power RF signals, the junction temperature rises significantly.

VSWR conditions that present short circuit loads to the part can cause significantly more power dissipation than with proper matching.

Special consideration needs to be made in the design of the PCB to properly dissipate the heat away from the part and maintain the 85°C maximum case temperature. It is recommended to use best design practices for high power QFN packages: multi-layer PCBs with thermal vias in a thermal pad soldered to the slug of the package. Special care also needs to be made to alleviate solder voiding under the part.

**Table 6. Theta JC**

Parameter	Min	Typ	Max	Unit
Theta JC (+85°C)		20		°C/W



## Evaluation Kit

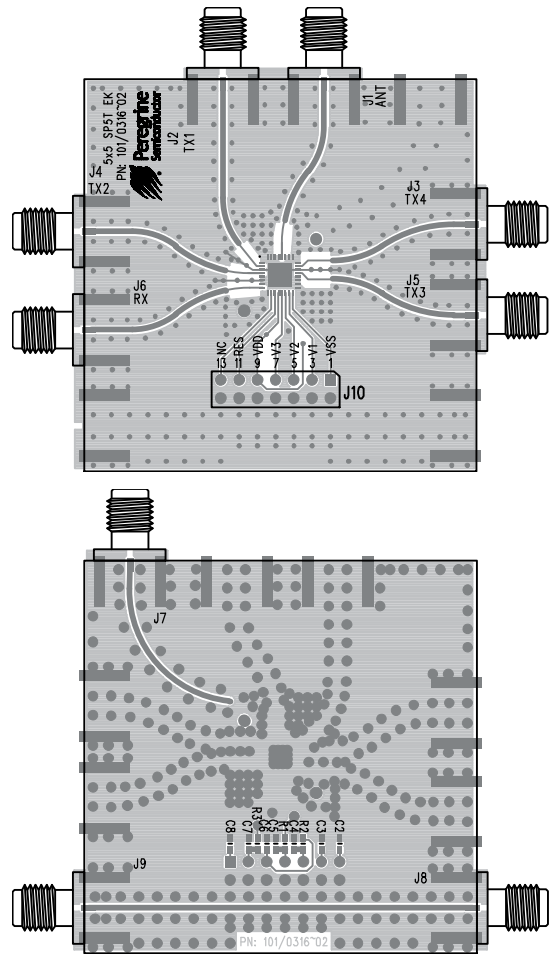
The PE42850 Evaluation Kit board was designed to ease customer evaluation of the PE42850 RF switch.

The evaluation board in Figure 23 was designed to test the part in the 5T configuration. DC power is supplied through J10, with  $V_{DD}$  on pin 9, and GND on the entire lower row of even numbered pins. To evaluate a switch path, add or remove jumpers on V1 (pin 3), V2 (pin 5), and V3 (pin 7) using *Table 5* (adding a jumper pulls the CMOS control pin low and removing it allows the on-board pull-up resistor to set the CMOS control pin high). Pins 11 and 13 of J10 are N/C.

The ANT port is connected through a 50 $\Omega$  transmission line via the top SMA connector, J1. RX and TX paths are also connected through 50 $\Omega$  transmission lines via SMA connectors. A 50 $\Omega$  through transmission line is available via SMA connectors J8 and J9. This transmission line can be used to estimate the loss of the PCB over the environmental conditions being evaluated. An open-ended 50 $\Omega$  transmission line is also provided at J7 for calibration if needed.

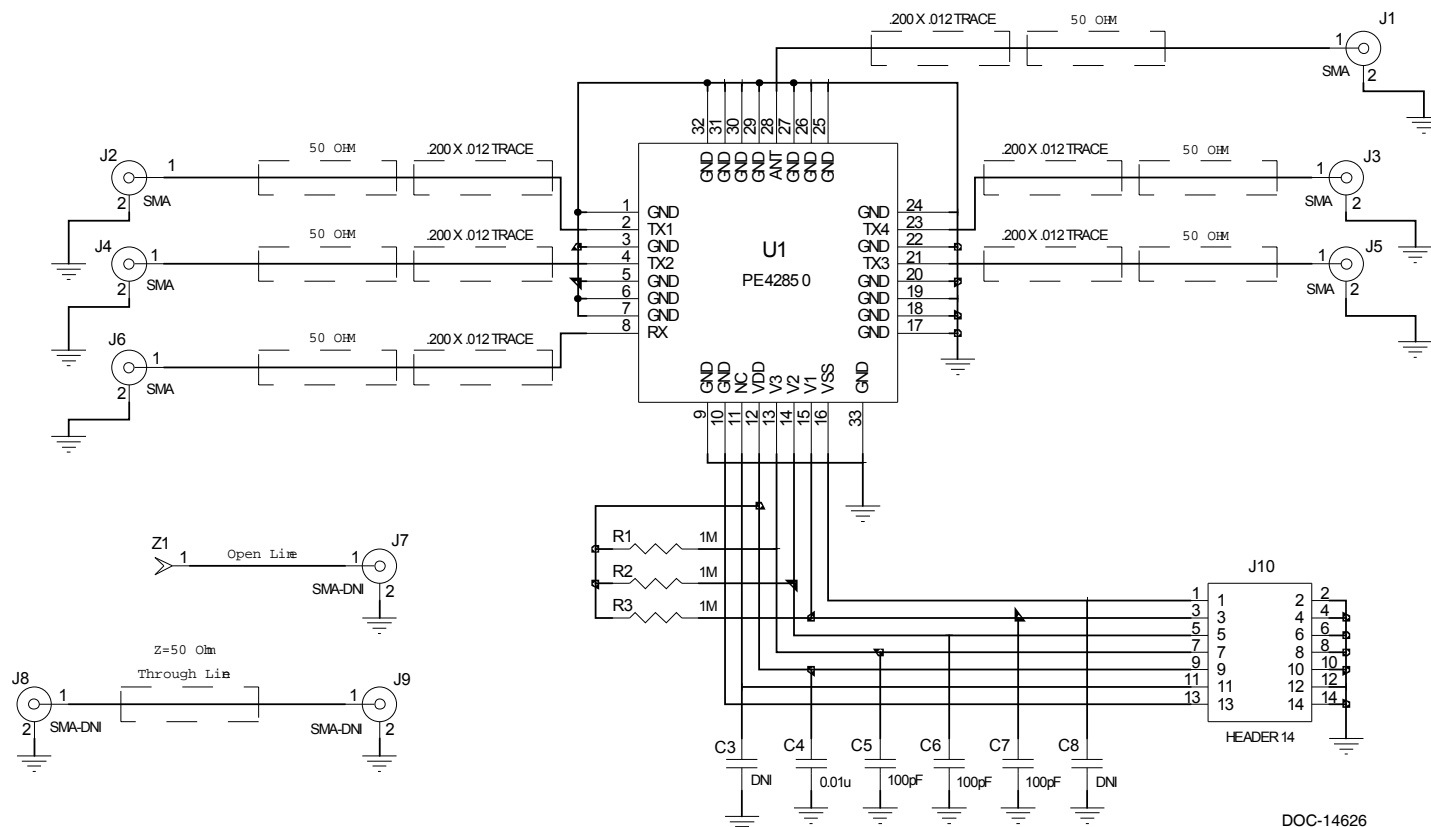
Narrow trace widths are used near each part to improve impedance matching.

**Figure 23. Evaluation Board Layouts**



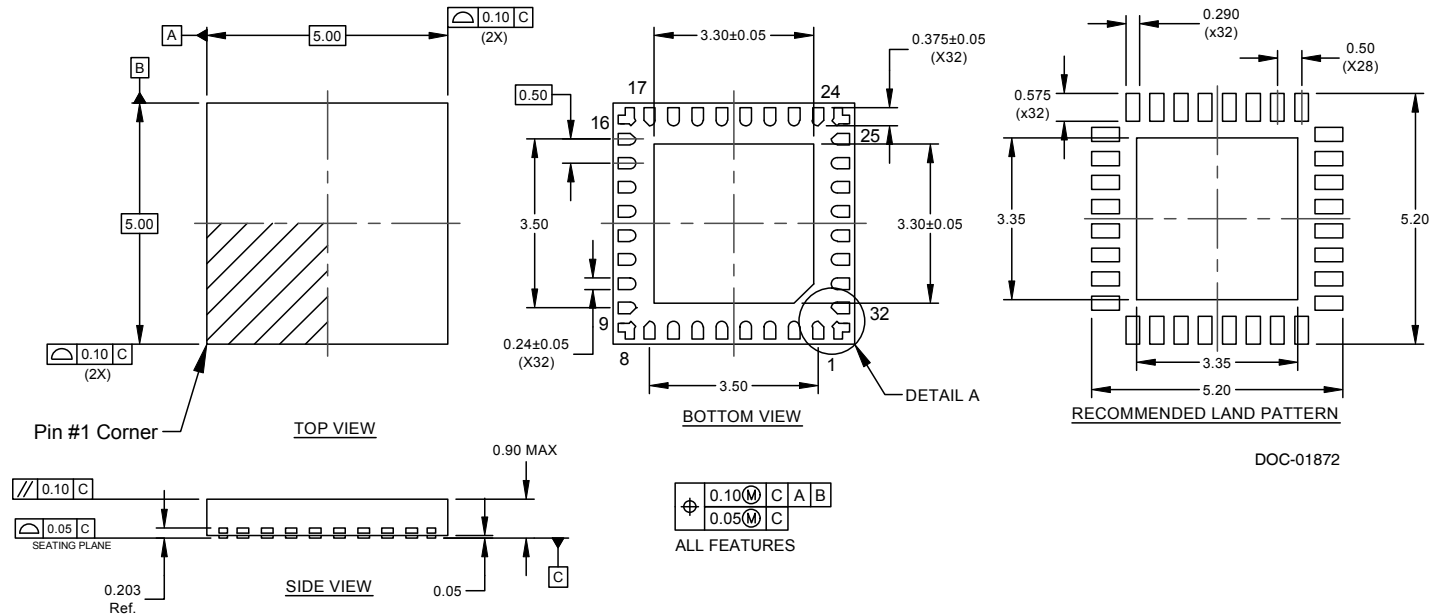
PRT-50283

### Figure 24. Evaluation Board Schematic



Notes: 1. Use 101-0316-02 PCB  
2. 32 mil Width, 10 mil Gaps, 28 mil Core, 4.3 Er, and 2.1 mil Cu

**Figure 25. Package Drawing**  
32-lead 5x5 mm QFN



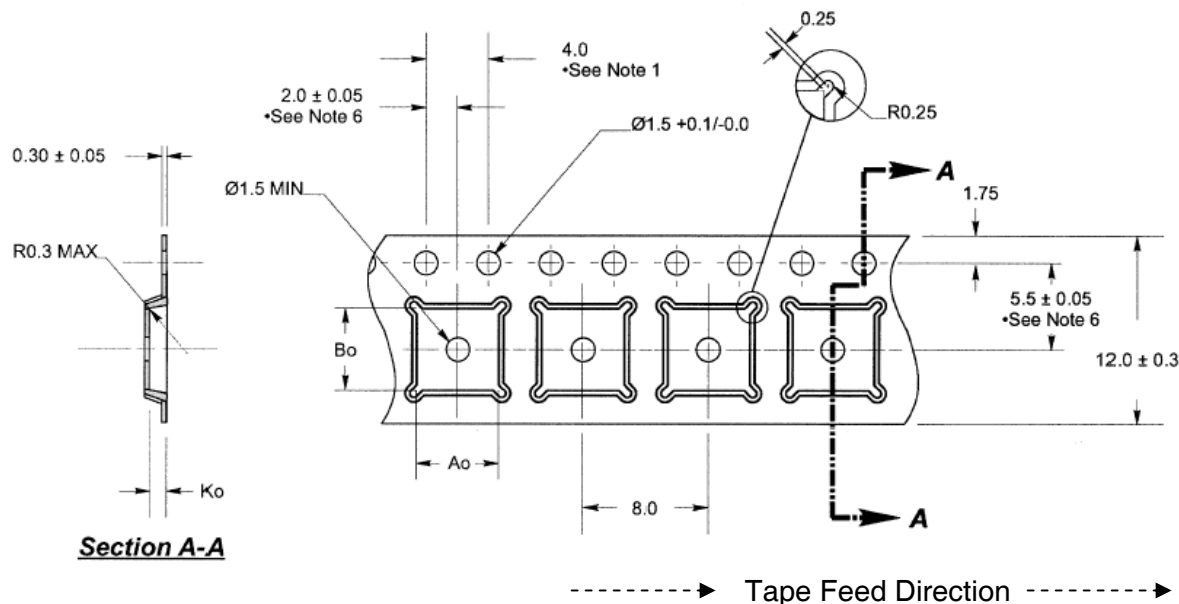
**Figure 26. Top Marking Specification**



17-0085

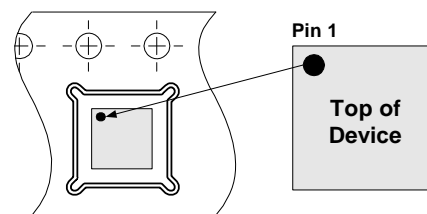
- = Pin 1 designator
- YYWW = Date code, last two digits of the year and work week
- ZZZZZZ = Six digits of the lot number

**Figure 27. Tape and Reel Drawing**



- Notes:
1. 10 sprocket hole pitch cumulative tolerance  $\pm 0.02$
  2. Camber not to exceed 1 mm in 100 mm
  3. Material: PS + C
  4.  $A_o$  and  $B_o$  measured as indicated
  5.  $K_o$  measured from a plane on the inside bottom of the pocket to the top surface of the carrier
  6. Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole

$A_o = 5.25$  mm  
 $B_o = 5.25$  mm  
 $K_o = 1.1$  mm



Device Orientation in Tape

**Table 7. Ordering Information**

Order Code	Description	Package	Shipping Method
PE42850MLBA-X	PE42850 SP5T RF switch	Green 32-lead 5x5 mm QFN	500 units / T&R
PE42850MLBA-Z	PE42850 SP5T RF switch	Green 32-lead 5x5 mm QFN	3000 units / T&R
EK42850-03	PE42850 Evaluation kit	Evaluation kit	1 / Box

## Sales Contact and Information

For sales and contact information please visit [www.psemi.com](http://www.psemi.com).

**Advance Information:** The product is in a formative or design stage. The datasheet contains design target specifications for product development. Specifications and features may change in any manner without notice.  
**Preliminary Specification:** The datasheet contains preliminary data. Additional data may be added at a later date. Peregrine reserves the right to change specifications at any time without notice in order to supply the best possible product.  
**Product Specification:** The datasheet contains final data. In the event Peregrine decides to change the specifications, Peregrine will notify customers of the intended changes by issuing a CNF (Customer Notification Form).  
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